

## **NCE N-Channel Super Trench Power MOSFET**

### **Description**

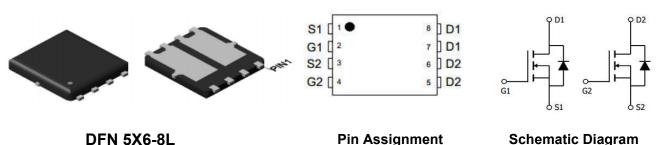
The NCEAP01ND35AG uses Super Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of R<sub>DS(ON)</sub> and Q<sub>g</sub>. This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

#### **General Features**

- V<sub>DS</sub> =100V,I<sub>D</sub> =35A  $R_{DS(ON)}$ =24m $\Omega$  (typical) @  $V_{GS}$ =10V  $R_{DS(ON)}$ =27m $\Omega$  (typical) @  $V_{GS}$ =4.5V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified



Pin Assignment

**Schematic Diagram** 

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP01ND35AG	NCEAP01ND35AG	DFN5X6-8L	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub> I <sub>D</sub> (100°C)	35	А
Diam Current-Continuous	I <sub>D</sub> (100℃)	24.5	Α
Pulsed Drain Current	I <sub>DM</sub>	140	Α
Maximum Power Dissipation	P <sub>D</sub>	60	W
Derating factor		0.4	W/℃
Single pulse avalanche energy (Note 1)	Eas	200	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

### **Thermal Characteristic**

	Thermal Resistance, Junction-to-Case	Rejc	2.5	°C/W			

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## Electrical Characteristics (Tc=25°C unless otherwise noted)

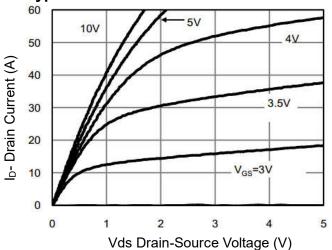
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	Igss	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	2.0	2.8	V
	Б	V <sub>GS</sub> =10V,I <sub>D</sub> =20A	-	24	28	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V,I <sub>D</sub> =20A	-	27	32	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	35	-	S
Dynamic Characteristics						
Input Capacitance	C <sub>lss</sub>	.,	-	1600	-	pF
Output Capacitance	Coss	$V_{DS}$ =50V, $V_{GS}$ =0V, F=1.0MHz	-	139	-	pF
Reverse Transfer Capacitance	Crss	r-1.0ivinz	-	11	-	pF
Switching Characteristics (Note 2)			•	,		
Turn-on Delay Time	t <sub>d(on)</sub>		-	6	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50 $V$ , $I_D$ =20 $A$	-	2	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =1.6 $\Omega$	-	18	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	2	-	nS
Total Gate Charge	Qg		-	26	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =50V,I <sub>D</sub> =20A,	-	7.4		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	3.8		nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =35A	-	-	1.2	V
Diode Forward Current	Is		-	-	35	Α
Reverse Recovery Time	e Recovery Time $t_{rr}$ $T_J = 25^{\circ}C$ , $I_F = 20^{\circ}$		-	-	26	nS
Reverse Recovery Charge	Qrr	di/dt = 500A/µs	-	-	98	nC
					1	

### Notes:

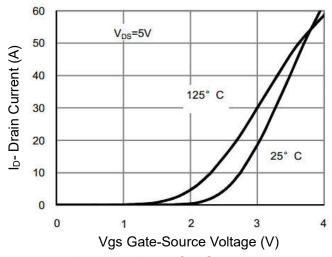
- 1. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.







**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

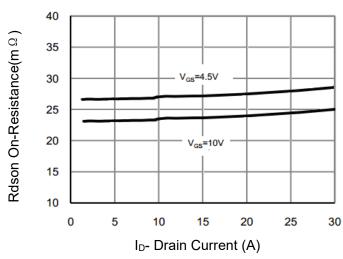


Figure 3 Rdson- Drain Current

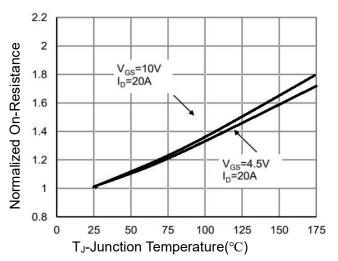


Figure 4 Rdson-Junction Temperature

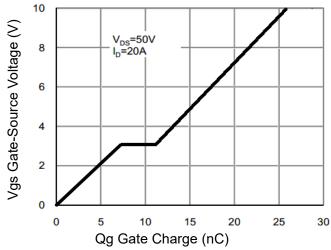


Figure 5 Gate Charge

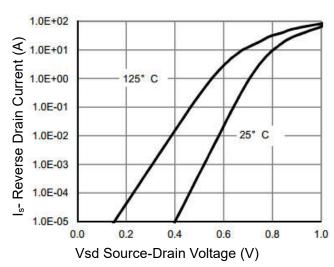


Figure 6 Source- Drain Diode Forward



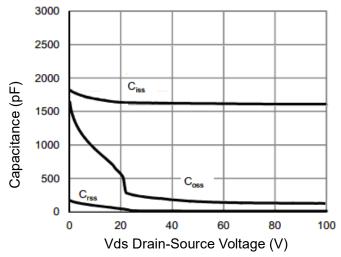


Figure 7 Capacitance vs Vds

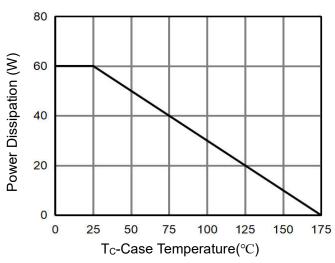


Figure 9 Power De-rating

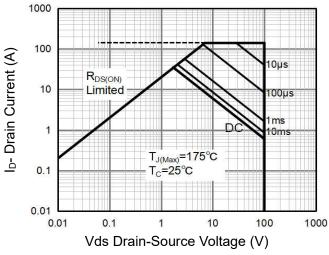


Figure 8 Safe Operation Area (Note3)

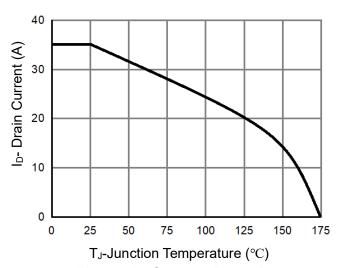


Figure 10 Current De-rating

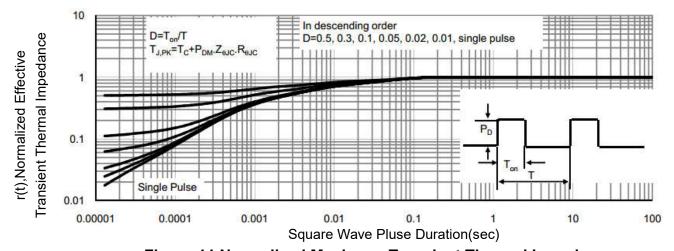
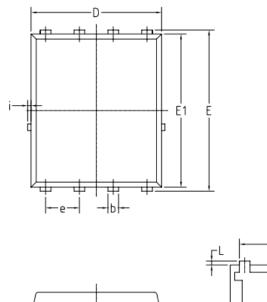
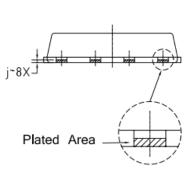


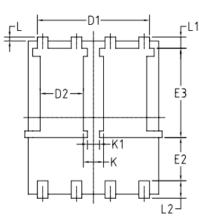
Figure 11 Normalized Maximum Transient Thermal Impedance



## **DFN5X6-8L Package Information**







S Y	COMMON					
M B O L	MM		INCH			
0 L	MIN.	MAX.	MIN.	MAX.		
Α	1.00	1.20	0.039	0.047		
Ь	0.30	0.50	0.012	0.020		
С	0.203 BSC		0.008	BSC		
D	4.80	5.00	0.189	0.197		
D1	4.06	4.36	0.160	0.172		
D2	1.47	1.77	0.058	0.070		
Е	5.90	6.20	0.232	0.244		
E1	5.65	5.85	0.222	0.230		
E2	1.45	_	0.057	_		
E3	3.20	3.50	0.126	0.138		
е	1.27 BSC		0.05 BSC			
L	0.05	0.25	0.002	0.010		
L1	0.325	0.525	0.013	0.021		
L2	0.500	0.800	0.020	0.031		
i	_	0.20	_	0.008		
K	0.61	0.91	0.024	0.036		
K1	0.31	0.60	0.012	0.024		
j	0.1015 BSC		0.004BSC			

# NCEAP01ND35AG

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